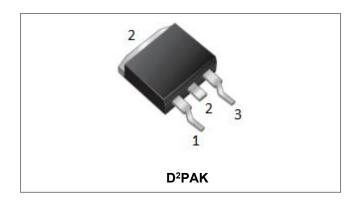






STB60H100C SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 100 | V |
| Average Rectified Forward Current (Per Device) | l _{F (AV)} | 50% duty cycle @Tc=105°C, rectangular wave form | 30(Per Leg) 60(Per Device) | Α |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse | 300 | Α |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-------------------------------------|-----------------|--|--------------|--------------|-------|
| Forward Voltage Drop (Per Leg) * | V _{F1} | @ 15A, Pulse, T _J = 25 °C @ 30A, Pulse, T _J = 25 °C | 0.72 0.87 | 0.75 0.90 | V |
| | V _{F2} | @ 15A, Pulse, T _J = 125 °C @ 30A, Pulse, T _J = 125 °C | 0.62 0.79 | 0.70 0.85 | V |
| Reverse Current (Per Leg) * | I _{R1} | $@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$ | 0.006 | 1 | mA |
| | I _{R2} | $@V_R = rated V_R$ $T_J = 125^{\circ}C$ | 2 | 15 | mA |
| Junction Capacitance(Per Leg) | C _T | $@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$ | 800 | - | pF |

^{*} Pulse width < 300 μs, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com
 sales@ smc-diodes.com



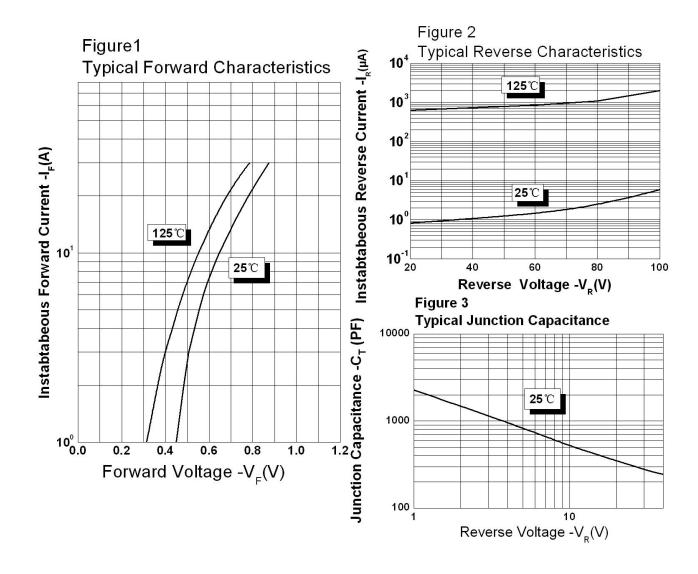




Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|--|--------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +175 | °C |
| Storage Temperature | T _{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case(Per Leg) | $R_{	heta JC}$ | DC operation | 2 | °C/W |
| Approximate Weight | wt | - | 1.85 | g |
| Case Style | D ² PAK | | | |

Ratings and Characteristics Curves



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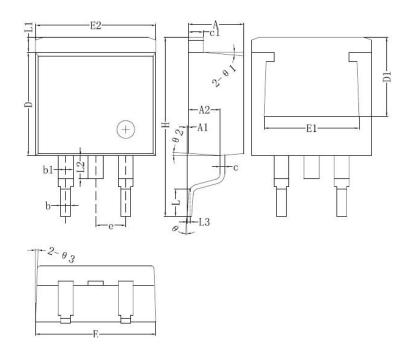
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Mechanical Dimensions D²PAK



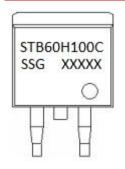
| Symbol | Dimensions in millimeters | | |
|--------|---------------------------|---------|-------|
| | Min. | Typical | Max. |
| Α | 4.47 | 4.70 | 4.85 |
| A1 | 0 | 0.10 | 0.25 |
| A2 | 2.59 | 2.69 | 2.89 |
| b | 0.71 | 0.81 | 0.96 |
| b1 | 1.17 | 1.27 | 1.37 |
| С | 0.31 | 0.38 | 0.61 |
| c1 | 1.17 | 1.27 | 1.37 |
| D | 8.50 | 8.70 | 8.90 |
| D1 | 6.40 | | |
| E | 10.01 | 10.16 | 10.31 |
| E1 | 7.6 | | |
| E2 | 9.98 | 10.08 | 10.31 |
| е | | 2.54 | |
| Н | 14.6 | 15.1 | 15.6 |
| L | 2.00 | 2.30 | 2.74 |
| L1 | 1.12 | 1.27 | 1.42 |
| L2 | 1.30 | | 2.20 |
| L3 | | 0.25BSC | |
| е | 0 | - | 8° |
| e1 | | 5° | |
| e2 | | 4° | |
| e3 | | 4° | |

Ordering Information

| Device | Package | Shipping |
|------------|--------------------|---------------|
| STB60H100C | D ² PAK | 800pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL
ST = Device Type
B = Package type

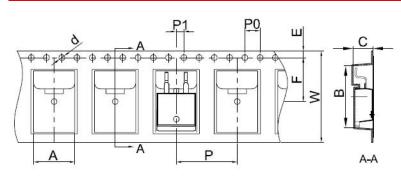
B = Package type 60 = Forward Current (60A) H = Tj 175°C 100 = Reverse Voltage(100V)

C = Configuration SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



| SYMBOL | Millimeters | | |
|----------|-------------|-------|--|
| STIVIBUL | Min. | Max. | |
| Α | 10.70 | 10.90 | |
| В | 16.03 | 16.23 | |
| С | 5.11 | 5.31 | |
| d | 1.45 | 1.65 | |
| Е | 1.65 | 1.85 | |
| F | 11.40 | 11.60 | |
| P0 | 3.90 | 4.10 | |
| Р | 15.90 | 16.10 | |
| P1 | 1.90 | 2.10 | |
| W | 23.90 | 24.30 | |

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